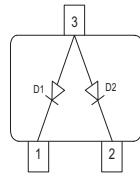
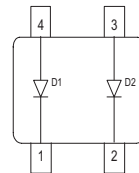
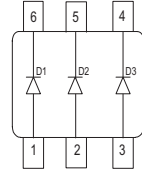


**Silicon Schottky Diodes**

- For mixer applications in the VHF / UHF range
- For high-speed switching applications
- Pb-free (RoHS compliant) package


**BAT68**

**BAT68-04  
BAT68-04W**

**BAT68-06  
BAT68-06W**

**BAT68-07W**

**BAT68-08S**


**ESD (Electrostatic discharge) sensitive device, observe handling precaution!**

| Type      | Package | Configuration   | $L_S$ (nH) | Marking |
|-----------|---------|-----------------|------------|---------|
| BAT68     | SOT23   | single          | 1.8        | 83s     |
| BAT68-04  | SOT23   | series          | 1.8        | 84s     |
| BAT68-04W | SOT323  | series          | 1.4        | 84s     |
| BAT68-06  | SOT23   | common anode    | 1.8        | 86s     |
| BAT68-06W | SOT323  | common anode    | 1.4        | 86s     |
| BAT68-07W | SOT343  | parallel pair   | 1.6        | 87s     |
| BAT68-08S | SOT363  | parallel triple | 1.4        | 83s     |

**Maximum Ratings** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

| Parameter                                                                                                                                                                                                      | Symbol           | Value                    | Unit |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|------------------|--------------------------|------|
| Diode reverse voltage                                                                                                                                                                                          | $V_R$            | 8                        | V    |
| Forward current                                                                                                                                                                                                | $I_F$            | 130                      | mA   |
| Total power dissipation<br>BAT68, $T_S \leq 77^\circ\text{C}$<br>BAT68-04, BAT68-06, $T_S \leq 61^\circ\text{C}$<br>BAT68-04W/-06W/-08S, $T_S \leq 92^\circ\text{C}$<br>BAT68-07W, $T_S \leq 89^\circ\text{C}$ | $P_{\text{tot}}$ | 150<br>150<br>150<br>150 | mW   |
| Junction temperature                                                                                                                                                                                           | $T_j$            | 150                      | °C   |
| Storage temperature                                                                                                                                                                                            | $T_{\text{stg}}$ | -55 ... 150              |      |

**Thermal Resistance**

| Parameter                                                                                                              | Symbol            | Value                                                | Unit |
|------------------------------------------------------------------------------------------------------------------------|-------------------|------------------------------------------------------|------|
| Junction - soldering point <sup>1)</sup><br>BAT68<br>BAT68-04, BAT68-06<br>BAT68-04W-BAT68-06W, BAT68-08S<br>BAT68-07W | $R_{\text{thJS}}$ | $\leq 490$<br>$\leq 590$<br>$\leq 390$<br>$\leq 410$ | K/W  |

**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

| Parameter                                                                             | Symbol            | Values   |            |            | Unit          |
|---------------------------------------------------------------------------------------|-------------------|----------|------------|------------|---------------|
|                                                                                       |                   | min.     | typ.       | max.       |               |
| Breakdown voltage<br>$I_{(\text{BR})} = 10 \mu\text{A}$                               | $V_{(\text{BR})}$ | 8        | -          | -          | V             |
| Reverse current<br>$V_R = 1 \text{ V}$<br>$V_R = 1 \text{ V}, T_A = 60^\circ\text{C}$ | $I_R$             | -<br>-   | -<br>-     | 0.1<br>1.2 | $\mu\text{A}$ |
| Forward voltage<br>$I_F = 1 \text{ mA}$<br>$I_F = 10 \text{ mA}$                      | $V_F$             | -<br>340 | 318<br>390 | 340<br>500 | mV            |

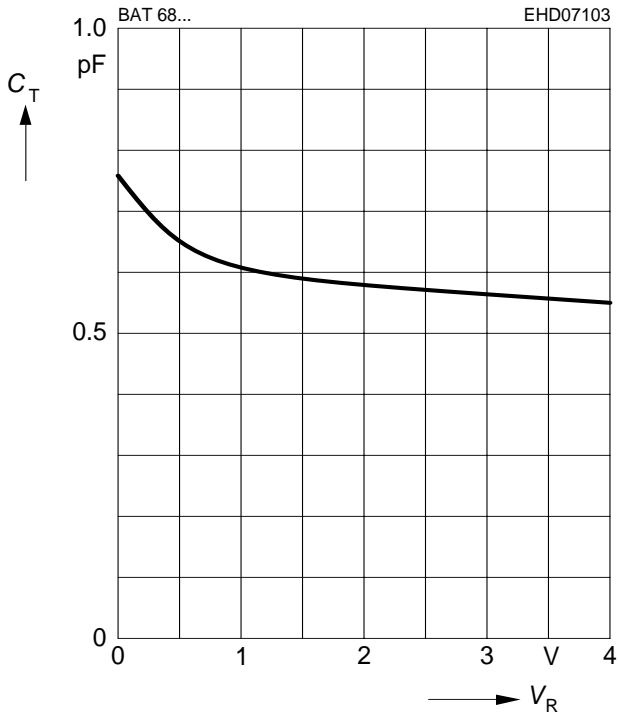
<sup>1)</sup>For calculation of  $R_{\text{thJA}}$  please refer to Application Note Thermal Resistance

**Electrical Characteristics** at  $T_A = 25^\circ\text{C}$ , unless otherwise specified

| Parameter                                                                   | Symbol | Values |      |      | Unit     |
|-----------------------------------------------------------------------------|--------|--------|------|------|----------|
|                                                                             |        | min.   | typ. | max. |          |
| <b>AC Characteristics</b>                                                   |        |        |      |      |          |
| Diode capacitance<br>$V_R = 0, f = 1 \text{ MHz}$                           | $C_T$  | -      | -    | 1    | pF       |
| Differential forward resistance<br>$I_F = 5 \text{ mA}, f = 10 \text{ kHz}$ | $R_F$  | -      | -    | 10   | $\Omega$ |

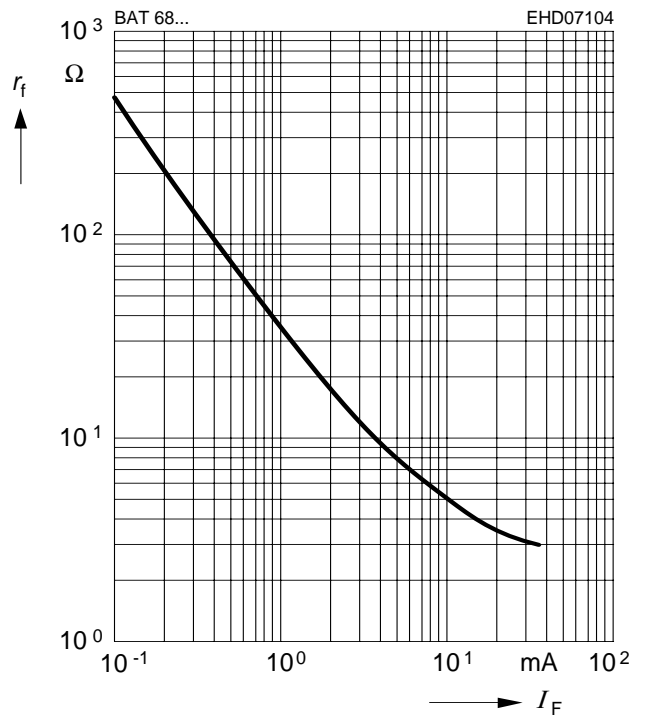
**Diode capacitance  $C_T = f(V_R)$**

$f = 1\text{MHz}$



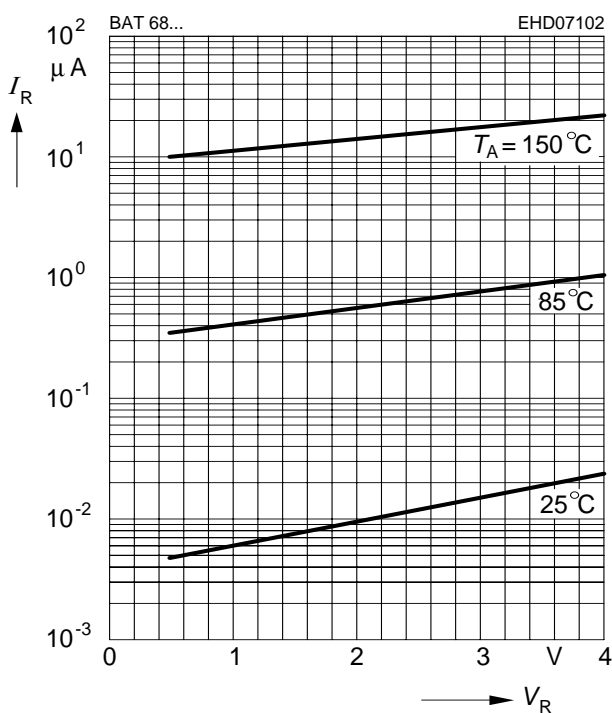
**Differential forward resistance  $r_f = f(I_F)$**

$f = 10\text{kHz}$



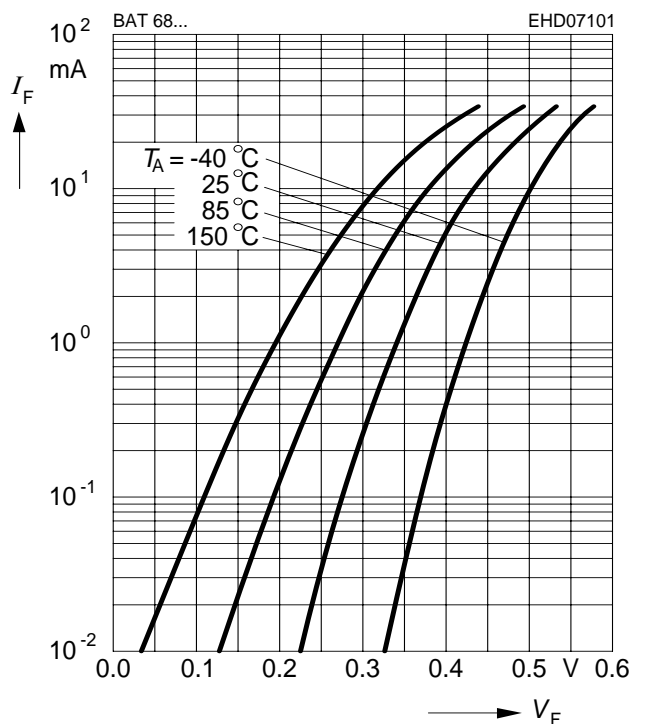
**Reverse current  $I_R = f(V_R)$**

$T_A = \text{Parameter}$



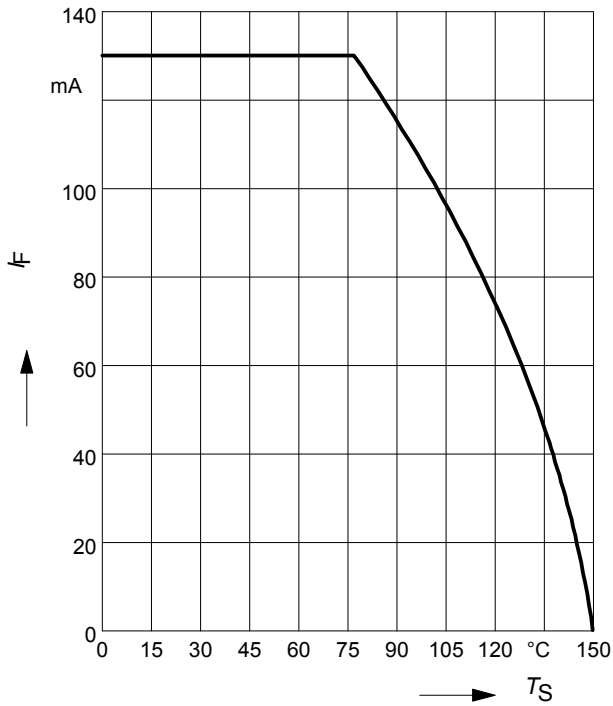
**Forward current  $I_F = f(V_F)$**

$T_A = \text{Parameter}$



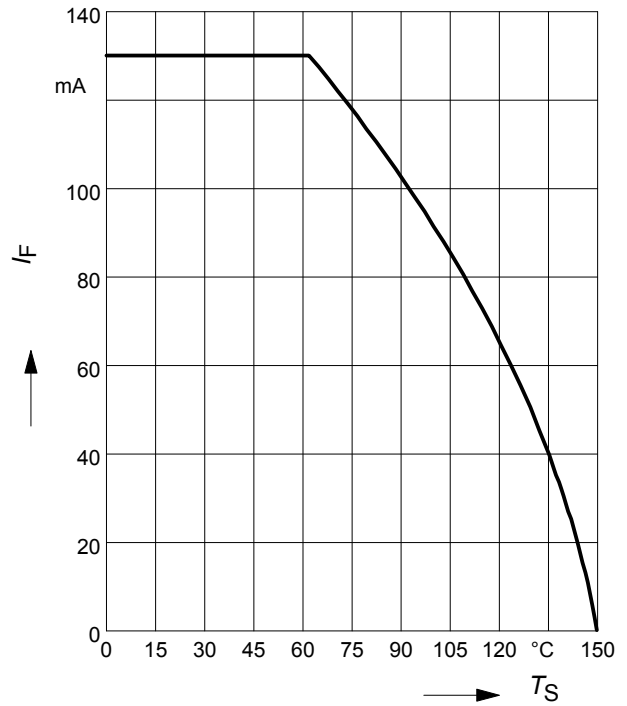
Forward current  $I_F = f(T_S)$

BAT68



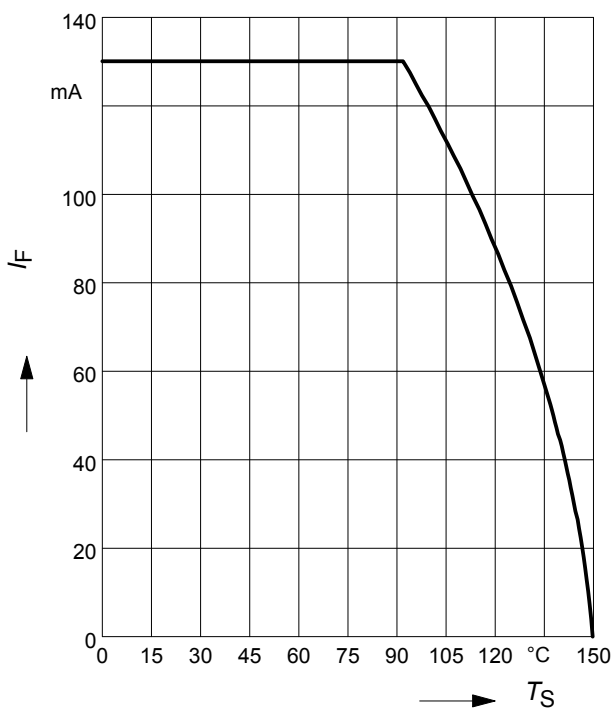
Forward current  $I_F = f(T_S)$

BAT68-04, BAT68-06



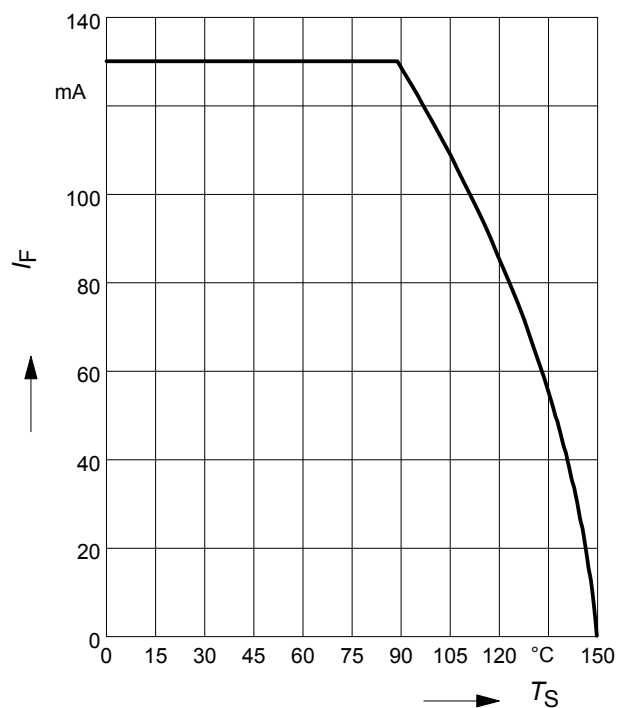
Forward current  $I_F = f(T_S)$

BAT68-04W, BAT68-06W, BAT68-08S



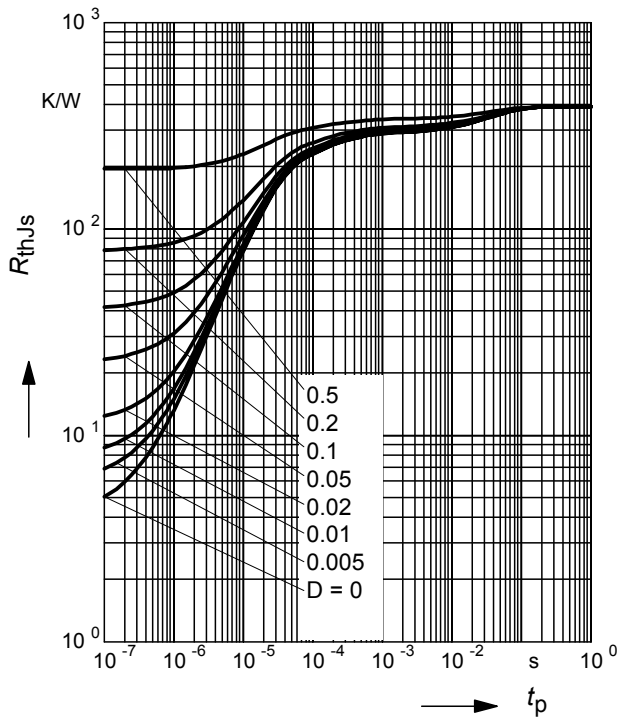
Forward current  $I_F = f(T_S)$

BAT68-07W



**Permissible Puls Load  $R_{thJS} = f(t_p)$**

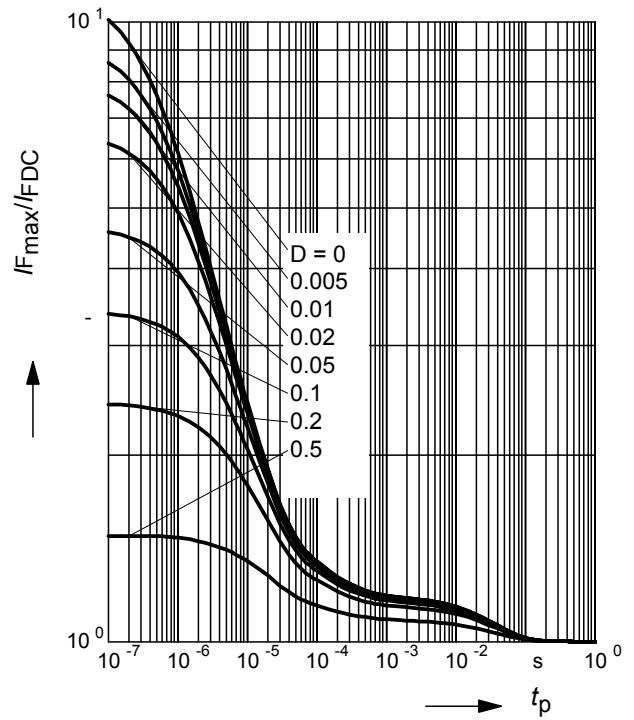
BAT68-04W, BAT68-06W



**Permissible Pulse Load**

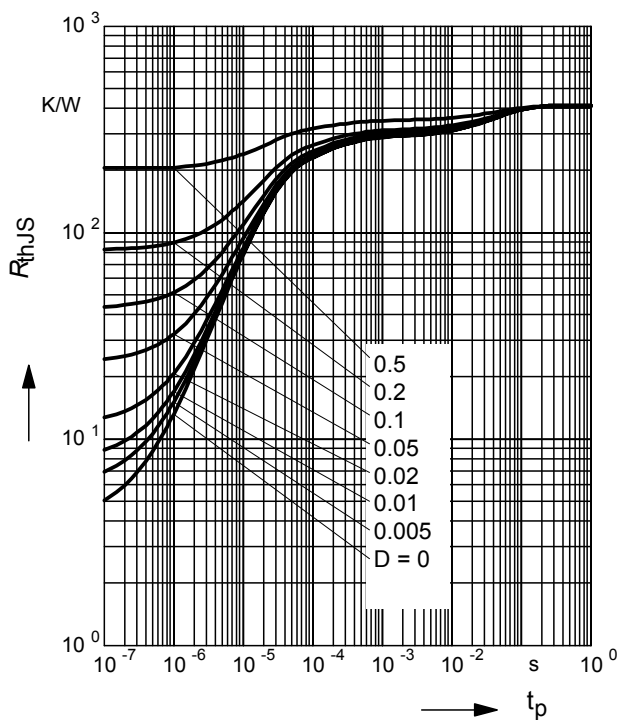
$I_{Fmax} / I_{FDC} = f(t_p)$

BAT68-04W, BAT68-06W



**Permissible Puls Load  $R_{thJS} = f(t_p)$**

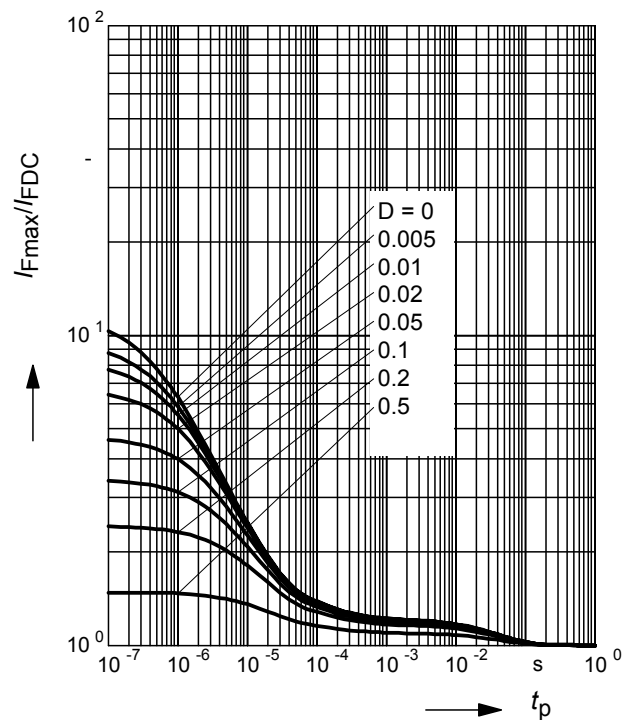
BAT68-07W



**Permissible Pulse Load**

$I_{Fmax} / I_{FDC} = f(t_p)$

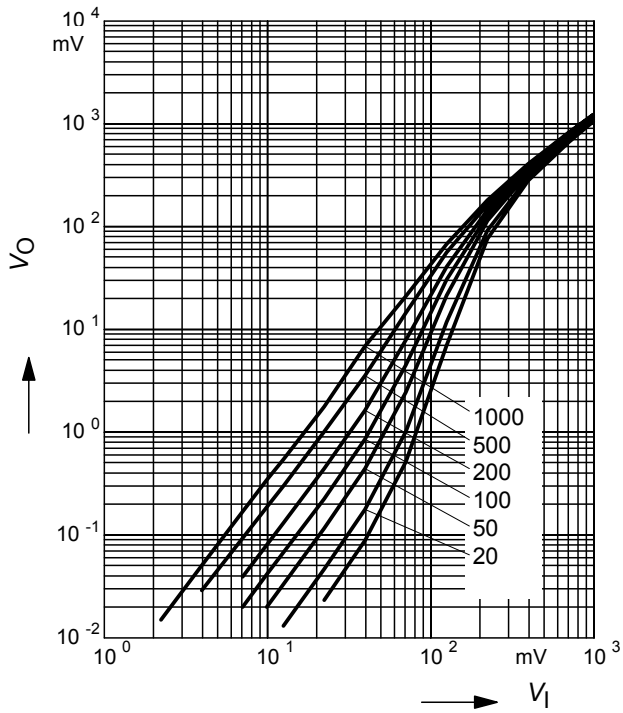
BAT68-07W



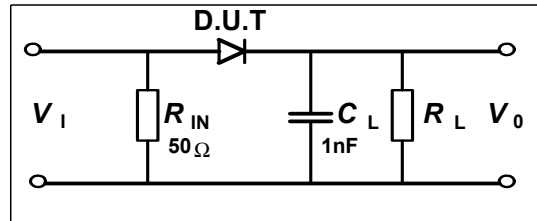
Rectifier voltage  $V_{out} = f(V_{in})$

$f = 900\text{MHz}$

$R_L =$  Parameter in  $k\Omega$



Testcircuit



Package Outline



1) Lead width can be 0.6 max. in dambar area

Foot Print

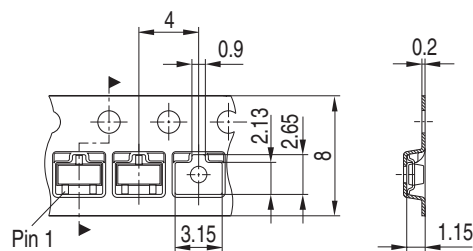


Marking Layout (Example)



Standard Packing

Reel  $\varnothing$ 180 mm = 3.000 Pieces/Reel  
 Reel  $\varnothing$ 330 mm = 10.000 Pieces/Reel





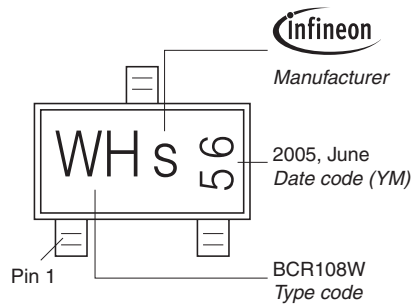
Package Outline



Foot Print

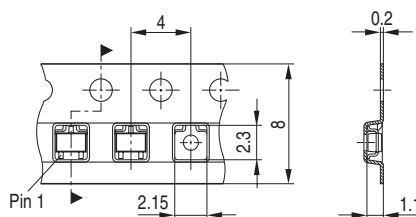


Marking Layout (Example)

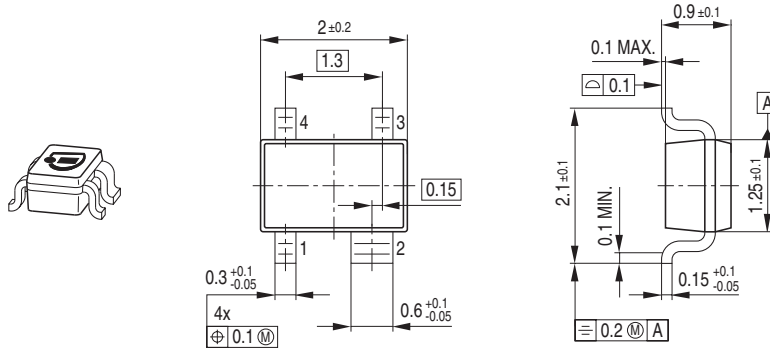


Standard Packing

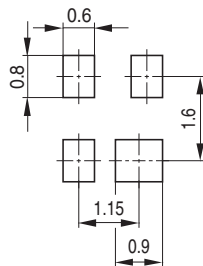
Reel ø180 mm = 3.000 Pieces/Reel  
 Reel ø330 mm = 10.000 Pieces/Reel



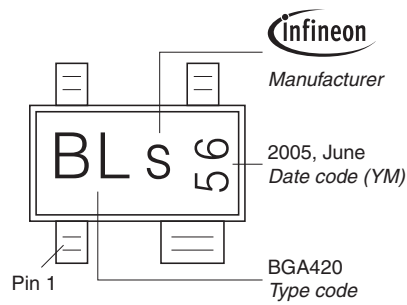
Package Outline



Foot Print

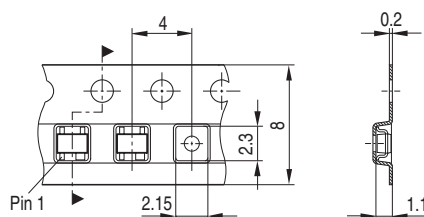


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel  
 Reel ø330 mm = 10.000 Pieces/Reel



Package Outline



Foot Print



Marking Layout (Example)

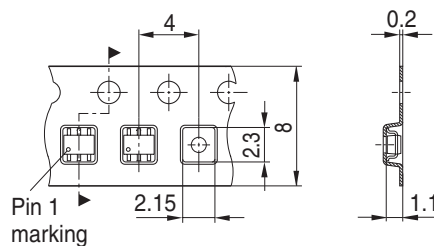
Small variations in positioning of Date code, Type code and Manufacture are possible.



Standard Packing

Reel  $\varnothing$ 180 mm = 3.000 Pieces/Reel  
 Reel  $\varnothing$ 330 mm = 10.000 Pieces/Reel

For symmetric types no defined Pin 1 orientation in reel.



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